	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	36	((light adj emitting adj diode) laser) and non adj uniform adj dop$4	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 13:31
2	BRS	L2	88	((light adj emitting adj diode) laser) and (graded adj dop$4)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 13:33

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	576	((light adj emitting adj diode) laser) and gainp and algainp	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 11:58
2	BRS	L2	114	1 and "111"	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 09:24
3	BRS	L3	79	2 and (quantum adj well)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 09:27
4	BRS	L4	68	3 and substrate and @ay<2000	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 09:28
5	BRS	L5	98	((light adj emitting adj diode) laser) and ingaas and ingaalas	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 10:45
6	BRS	L6	345	((light adj emitting adj diode) laser) and znsse	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 10:45

	Type	L #	Hits	Search Text	DBs	Time Stamp
7	BRS	L7	16	6 and 0001	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 10:56
8	BRS	L8	16	6 and (0001)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 10:56
9	BRS	L9	4911	((light adj emitting adj diode) laser) and hexagonal	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 11:12
10	BRS	L10	9	9 and 0001	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 11:13
11	BRS	L11	9	10 and ("100" 001)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 11:14
12	BRS	L12	11	((light adj emitting adj diode) laser) and znsse and hexagonal	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 11:21

	Type	L #	Hits	Search Text	DBs	Time Stamp
13	BRS	L13	499	((light adj emitting adj diode) laser) and gainp and algainp and clad$4	USPAT; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 11:59